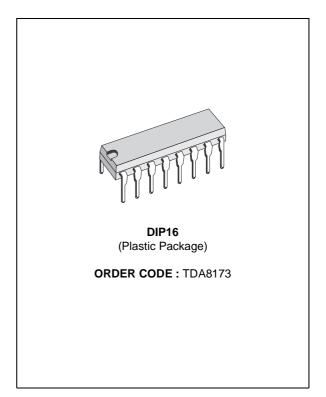


TDA8173

TV VERTICAL DEFLECTION OUTPUT CIRCUIT

- POWER AMPLIFIER
- FLYBACK GENERATOR
- THERMAL PROTECTION
- REFERENCE VOLTAGE



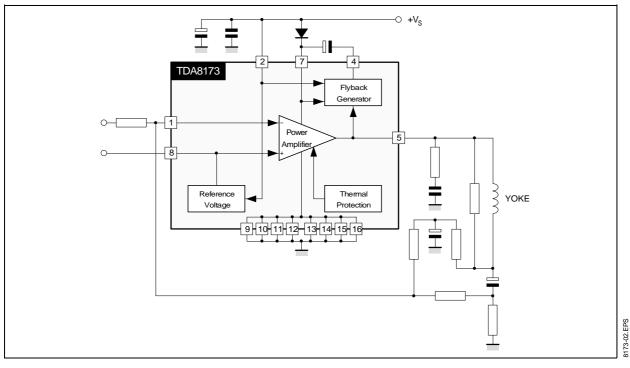
DESCRIPTION

The TDA8173 is a monolithic integrated circuit in POWERDIP package. It is a high efficiency power booster for direct driving of vertical windings of TV yokes. It is intended for use in Color and B & W television sets as well as in monitors, and displays.

PIN CONNECTIONS (top view)

INVERTING INPUT	1 16 2 15 3 14 4 13 5 12 6 11 7 10 8 9

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
Vs	Supply Voltage (pin 2)	35	V	
V_5	Flyback Peak Voltage	60	V	
V ₄	Voltage at Pin 4	+ Vs		
V_1, V_8	Amplifier Input Voltage	+ V _s - 0.5	V	
lo	Output Peak Current (non repetitive, t = 2 ms)	2.5	А	
lo	Output Peak Current at f = 50 or 60 Hz, $t \le 10 \ \mu s$	3	А	
lo	Output Peak Current at f = 50 or 60 Hz, $t > 10 \mu s$	2	А	
I 4	Pin 4 DC Current at $V_5 < V_2$	100	mA	
I ₄	Pin 4 Peak to Peak Flyback Current at f = 50 or 60 Hz, $t_{fly} \le 1.5$ ms	3	А	
P _{tot}	Total Power Dissipation at T _{case} = 60 °C	6	W	
T _{stg} , T _j	Storage and Junction Temperature	- 40 to 150	°C	

THERMAL DATA

Symbol	Parameter	Value	Unit	
R _{th (j-c)}	Thermal Resistance Junction-case Max.	15	°C/W	02.TBI
R _{th (j–a)}	Thermal Resistance Junction-ambient Max.	70	°C/W	8173-(

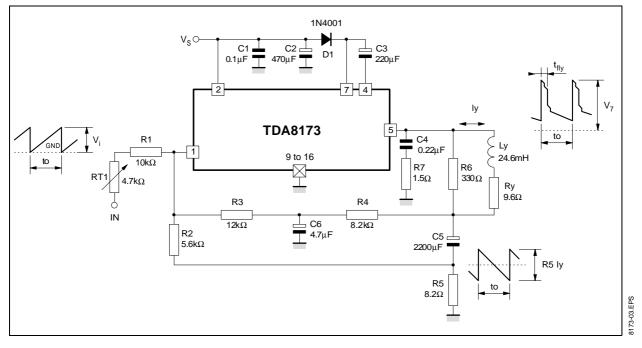


ELECTRICAL CHARACTERISTICS

(refer to the test circuits, $V_S = 35V$, $T_{amb} = 25^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
l ₂	Pin 2 Quiescent Current	$I = 0, I_5 = 0$		8	16	mA
I ₇	Pin 7 Quiescent Current	$I = 0, I_5 = 0$		16	36	mA
I ₁	Amplifier Input Bias Current	V ₁ = 1 V		- 0.1	- 1	μΑ
V _{4L}	Pin 4 Saturation Voltage to GND	l ₄ = 20 mA		1		V
V_5	Quiescent Output Voltage	V_s = 35 V, R_a = 39 k Ω		18		V
V _{5L} Output Saturation Voltage to GN	Output Saturation Voltage to GND	I ₅ = 1.2 A		1	1.4	V
		I ₅ = 0.7 A		0.7	1	V
V_{5H}	Output Saturation Voltage to Supply	– I ₅ = 1.2 A		1.6	2.2	V
		$-I_5 = 0.7 \text{ A}$		1.3	1.8	V
Tj	Junction Temperature for Thermal Shut Down			140		°C
V ₈	Reference Voltage			2.2		V
$\frac{\Delta V_8}{\Delta V_S}$	Reference Voltage Drift versus Supply Voltage	$V_s = 15 \text{ to } 30 \text{ V}$		1	2	mV

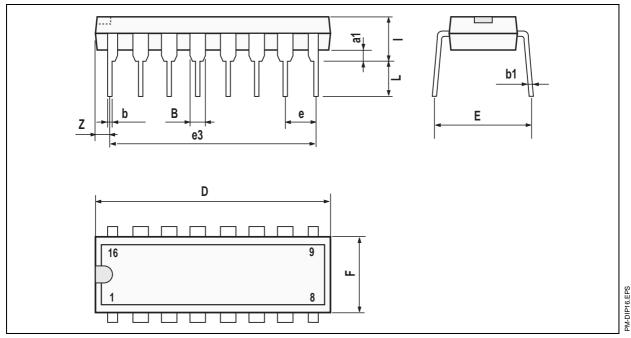
TEST CIRCUITS





PACKAGE MECHANICAL DATA

16 PINS - PLASTIC DIP



Dimensions		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
a1	0.51			0.020		
В	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
е		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

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